NSN 5961-01-165-5170

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-165-5170 **Inclosure Material:** Metal **Overall Length:** 0.050 inches **Overall Diameter:** 0.055 inches **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 3.0 breakdown voltage, dc **Power Rating Per Characteristic:** 100.0 milliwatts small-signal input power, common-collector preset **Capacitance Rating In Picofarads:** 0.08 **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 bonding pad Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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